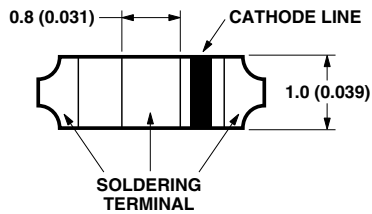
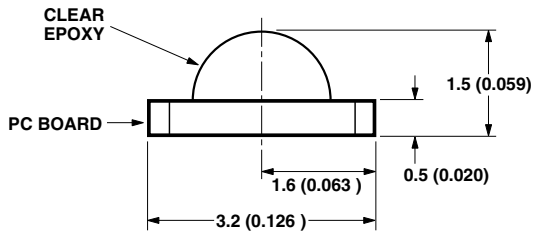
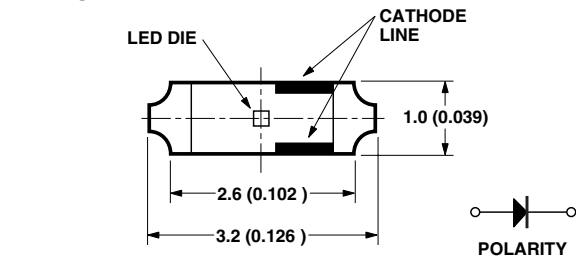
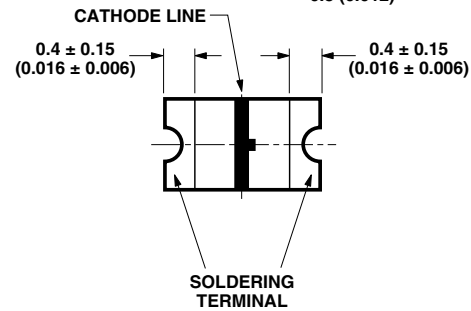
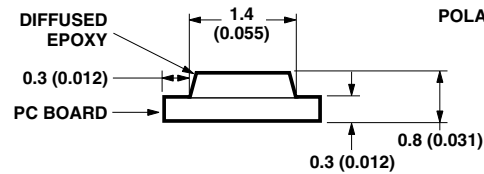
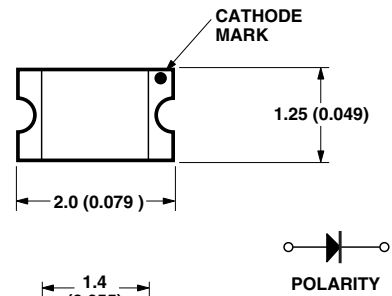


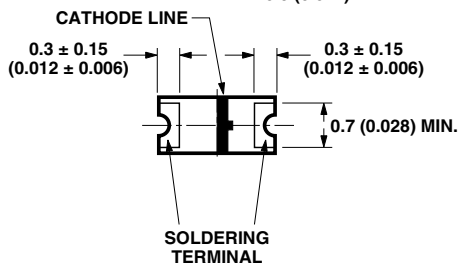
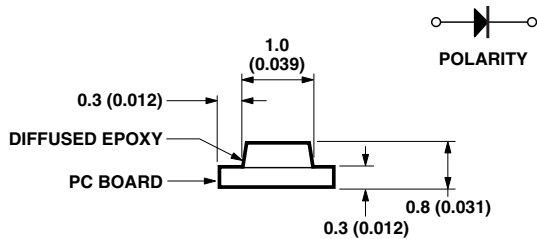
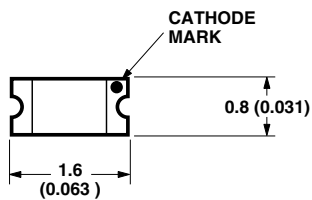
Package Dimensions



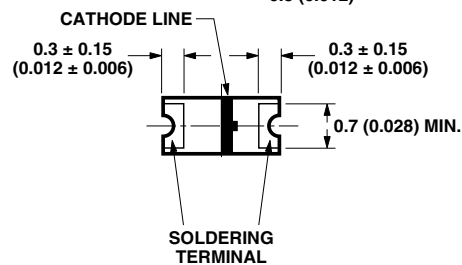
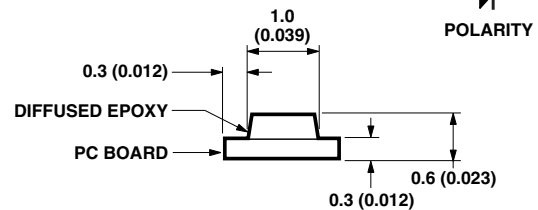
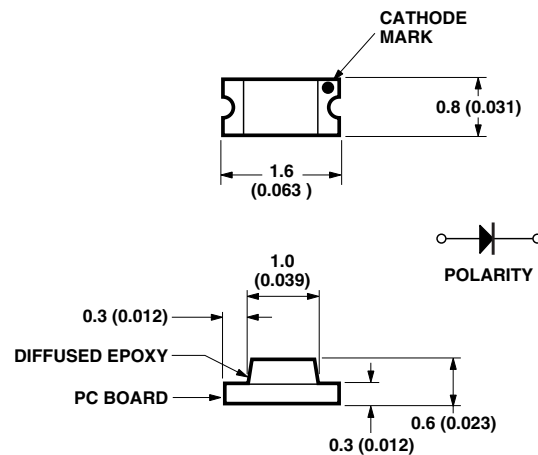
HSMx-C110



HSMx-C170



HSMx-C190

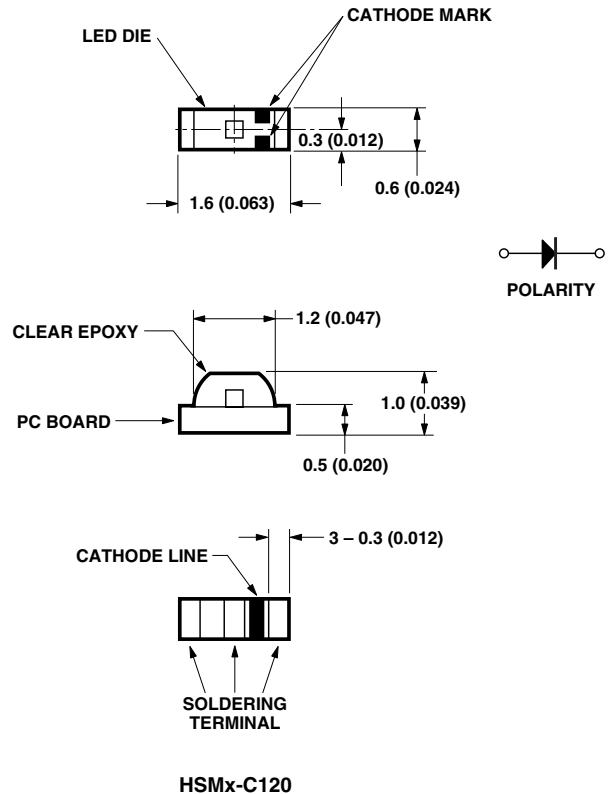
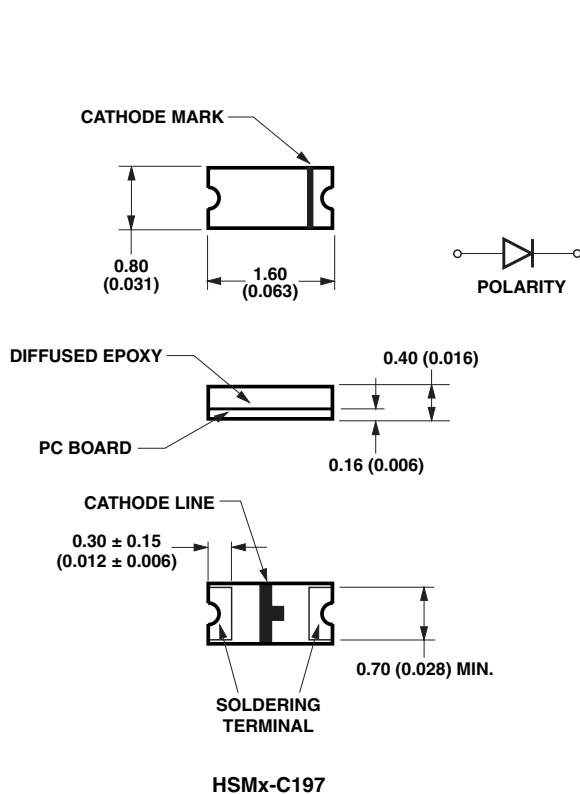
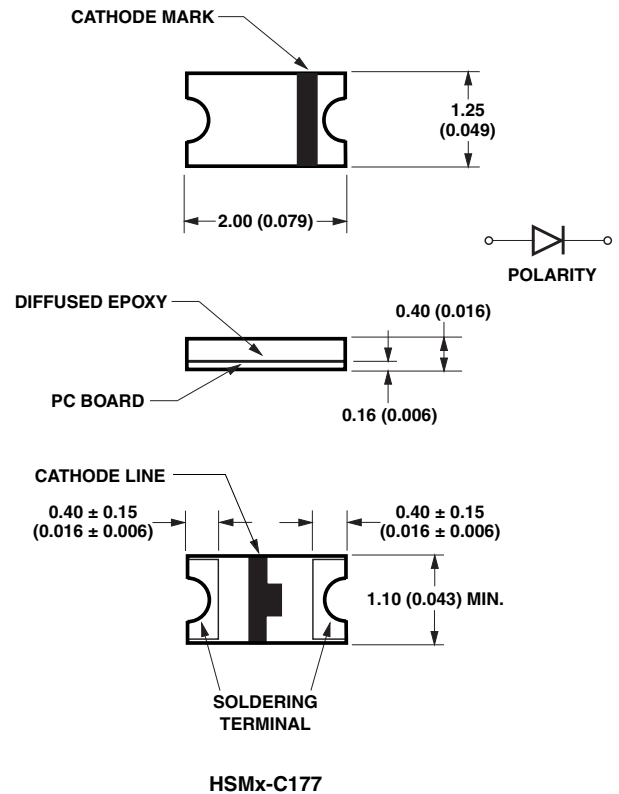
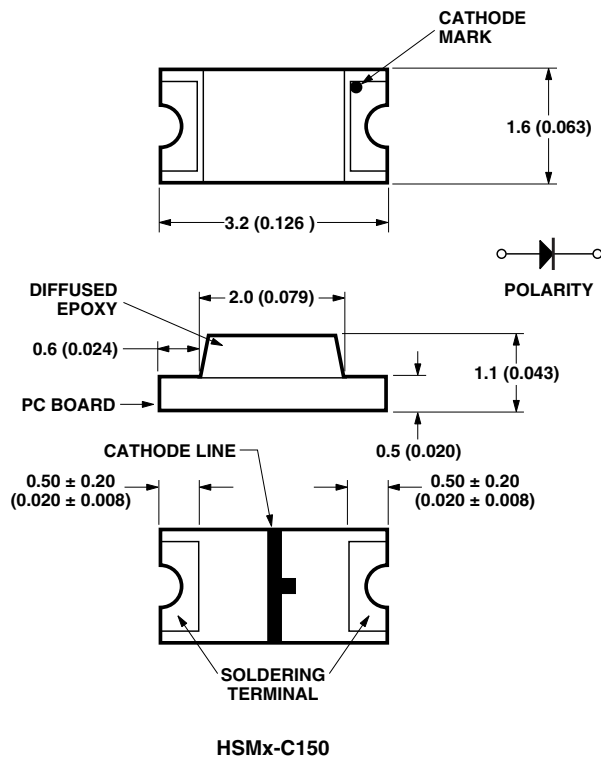


HSMx-C191

NOTES:

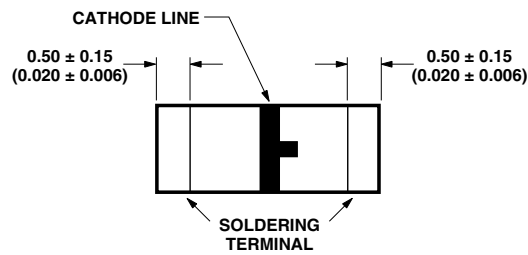
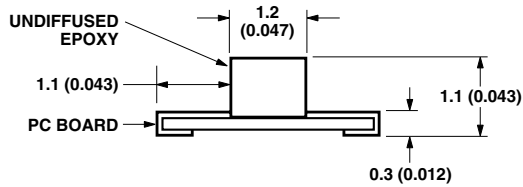
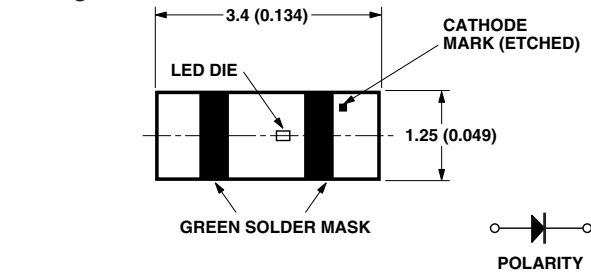
1. ALL DIMENSIONS IN MILLIMETERS (INCHES).
2. TOLERANCE IS ± 0.1 mm (± 0.004 IN.) UNLESS OTHERWISE SPECIFIED.

Package Dimensions, continued

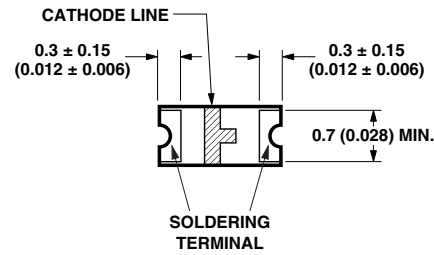
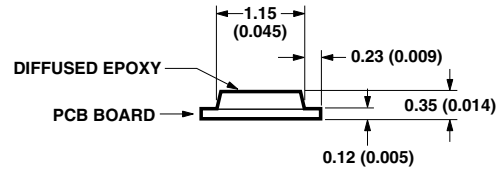
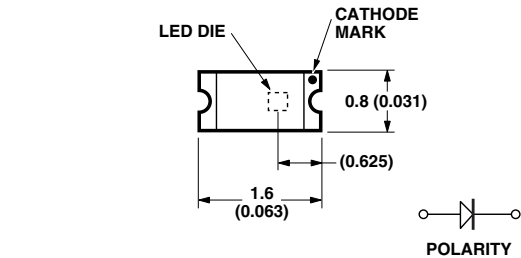


- NOTES:**
1. ALL DIMENSIONS IN MILLIMETERS (INCHES).
 2. TOLERANCE IS ± 0.1 mm (± 0.004 IN.) UNLESS OTHERWISE SPECIFIED.

Package Dimensions, continued



HSMx-C265



HSMx-C130

NOTES:

1. ALL DIMENSIONS IN MILLIMETERS (INCHES).
2. TOLERANCE IS ± 0.1 mm (± 0.004 IN.) UNLESS OTHERWISE SPECIFIED.

Device Selection Guide

Package Dimension (mm) ^{[1], [2]}	InGaN Green	InGaN Blue	Package Description
3.2(L) x 1.5(W) x 1.0(H)	HSMQ-C110	HSMR-C110	Untinted, Non-diffused
1.6(L) x 1.0(W) x 0.6(H)	HSMQ-C120	HSMR-C120	Untinted, Non-diffused
1.6(L) x 0.8(W) x 0.35(H)	–	HSMR-C130	Untinted, Diffused
3.2(L) x 1.6(W) x 1.1(H)	HSMQ-C150	HSMR-C150	Untinted, Diffused
2.0(L) x 1.25(W) x 0.8(H)	HSMQ-C170	HSMR-C170	Untinted, Diffused
2.0(L) x 1.25(W) x 0.4(H)	HSMQ-C177	HSMR-C177	Untinted, Diffused
1.6(L) x 0.8(W) x 0.8(H)	HSMQ-C190	HSMR-C190	Untinted, Diffused
1.6(L) x 0.8(W) x 0.6(H)	HSMQ-C191	HSMR-C191	Untinted, Diffused
1.6(L) x 0.8(W) x 0.4(H)	HSMQ-C197	HSMR-C197	Untinted, Diffused
3.4(L) x 1.25(W) x 1.1(H)	HSMQ-C265	HSMR-C265	Untinted, Non-diffused

Notes: 1. Dimensions in mm. 2. Tolerance ± 0.1 mm unless otherwise noted.

Absolute Maximum Ratings at $T_A = 25^\circ\text{C}$

Parameter	HSMQ-Cxxx HSMR-Cxxx	Units
DC Forward Current ^[1]	20	mA
Power Dissipation	78	mW
Reverse Voltage ($I_R = 100 \mu\text{A}$)	5	V
LED Junction Temperature	95	$^\circ\text{C}$
Operating Temperature Range	-40 to +85	$^\circ\text{C}$
Storage Temperature Range	-40 to +85	$^\circ\text{C}$
Soldering Temperature	See reflow soldering profile (Figures 11 & 12)	

Note: 1. Derate linearly as shown in Figure 4.

Electrical Characteristics at T_A = 25 °C

Part Number	Forward Voltage V _F (Volts) @ I _F = 20 mA @ I _R = 100 µA		Reverse Breakdown V _R (Volts) f = 1 MHz	Capacitance C (pF), V _F = 0, R _{θJ-PIN} (°C/W)	Thermal Resistance
	Typ.	Max.	Min.	Typ.	Typ.
HSMQ-C110/C150	3.4	3.9	5	140	450
HSMR-C110/C150	3.4	3.9	5	140	450
HSMQ-C120	3.4	3.9	5	100	450
HSMR-C120/C130	3.4	3.9	5	100	450
HSMQ-C170/C190/C191	3.4	3.9	5	110	300
HSMR-C170/C190/C191	3.4	3.9	5	110	300
HSMQ-C177/C197	3.4	3.9	5	110	350
HSMR-C177/C197	3.4	3.9	5	110	350
HSMQ-C265	3.4	3.9	5	65	300
HSMR-C265	3.4	3.9	5	65	300

V_F Tolerance: ±0.1 V

Optical Characteristics at T_A = 25 °C

Part Number	Color	Luminous Intensity I _V (mcd) @ 20 mA ^[1]		Color, Peak Wavelength λ _{peak} (nm)	Viewing Dominant Wavelength λ _d ^[2] (nm)	Luminous Angle 2 θ _{1/2} Degrees ^[3]	Efficacy η _v (lm/w)
		Min.	Typ.	Typ.	Typ.	Typ.	Typ.
HSMQ-C110	Green	45	150	520	527	130	500
HSMQ-C120	Green	45	145	520	527	155	500
HSMQ-C150/170/190/191	Green	45	145	520	527	140	500
HSMQ-C177/197	Green	45	145	520	527	130	500
HSMQ-C265	Green	45	140	520	527	150	500
HSMR-C110	Blue	18	60	469	473	130	88
HSMR-C120	Blue	18	55	469	473	155	88
HSMR-C130	Blue	18	55	469	473	145	88
HSMR-C150/170/190/191	Blue	18	55	469	473	140	88
HSMR-C177/197	Blue	18	55	469	473	130	88
HSMR-C265	Blue	18	45	469	473	150	88

Notes:

1. The luminous intensity, I_V, is measured at the peak of the spatial radiation pattern which may not be aligned with the mechanical axis of the lamp package.
2. The dominant wavelength, λ_d, is derived from the CIE Chromaticity Diagram and represents the perceived color of the device.
3. θ_{1/2} is the off-axis angle where the luminous intensity is 1/2 the peak intensity.

Color Bin Limits^[1]

Blue Color Bins^[1]

Bin ID	Dom. Wavelength (nm)	
	Min.	Max.
A	460.0	465.0
B	465.0	470.0
C	470.0	475.0
D	475.0	480.0

Tolerance: ±1 nm

Note:

1. Bin categories are established for classification of products. Products may not be available in all categories. Please contact your Avago representative for information on currently available bins.

InGaN Green Color Bins^[1]

Bin ID	Dom. Wavelength (nm)	
	Min.	Max.
A	515.0	520.0
B	520.0	525.0
C	525.0	530.0
D	530.0	535.0

Tolerance: ±1 nm

Light Intensity (Iv) Bin Limits^[1]

Bin ID	Intensity (mcd)		Bin ID	Intensity (mcd)	
	Min.	Max.		Min.	Max.
A	0.11	0.18	N	28.50	45.00
B	0.18	0.29	P	45.00	71.50
C	0.29	0.45	Q	71.50	112.50
D	0.45	0.72	R	112.50	180.00
E	0.72	1.10	S	180.00	285.00
F	1.10	1.80	T	285.00	450.00
G	1.80	2.80	U	450.00	715.00
H	2.80	4.50	V	715.00	1125.00
J	4.50	7.20	W	1125.00	1800.00
K	7.20	11.20	X	1800.00	2850.00
L	11.20	18.00	Y	2850.00	4500.00
M	18.00	28.50			

Tolerance: $\pm 15\%$

Notes:

- Bin categories are established for classification of products. Products may not be available in all categories. Please contact your Avago representative for information on currently available bins.
- The Iv binning specification set-up is for lowest allowable Iv binning only. There are no upper Iv bin limits.

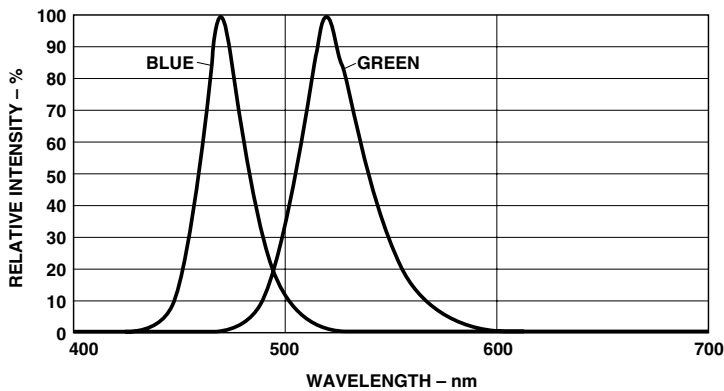


Figure 1. Relative intensity vs. wavelength.

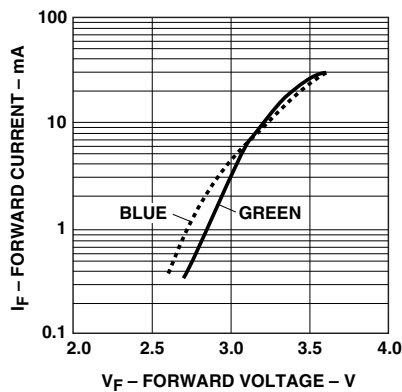


Figure 2. Forward current vs. forward voltage.

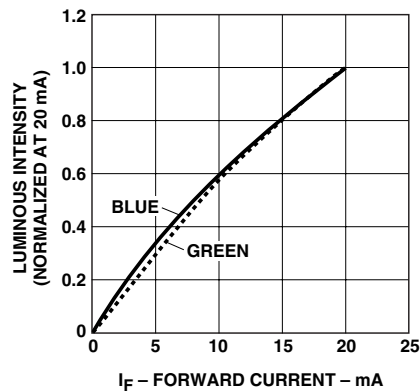


Figure 3. Luminous intensity vs. forward current.

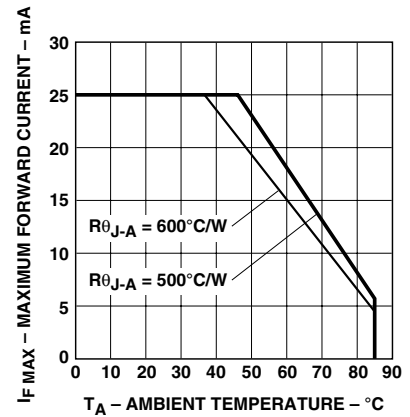


Figure 4. Maximum forward current vs. ambient temperature.

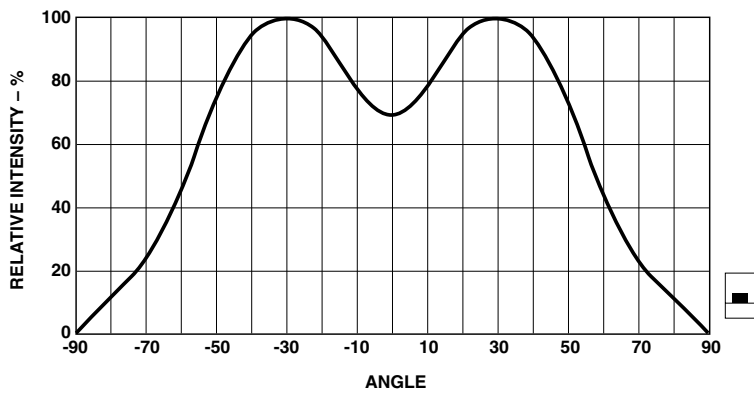
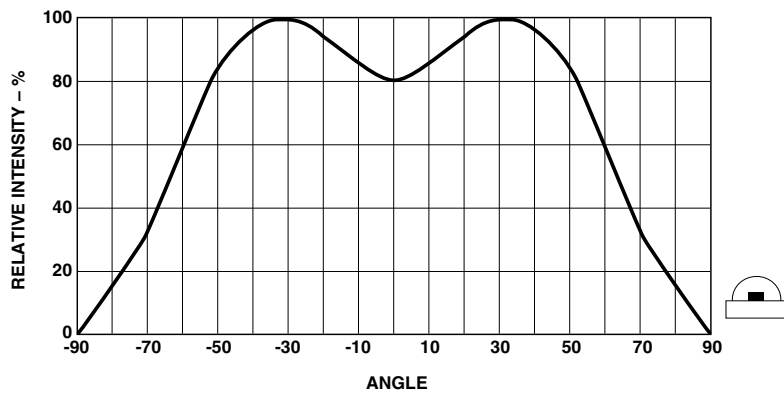


Figure 5. Relative intensity vs. angle for HSMx-C110.

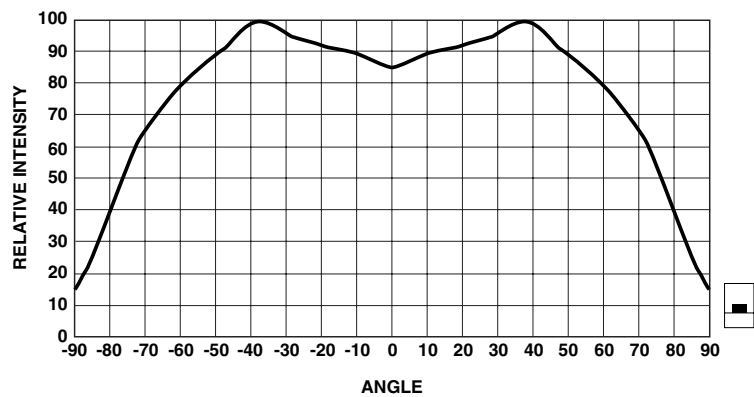
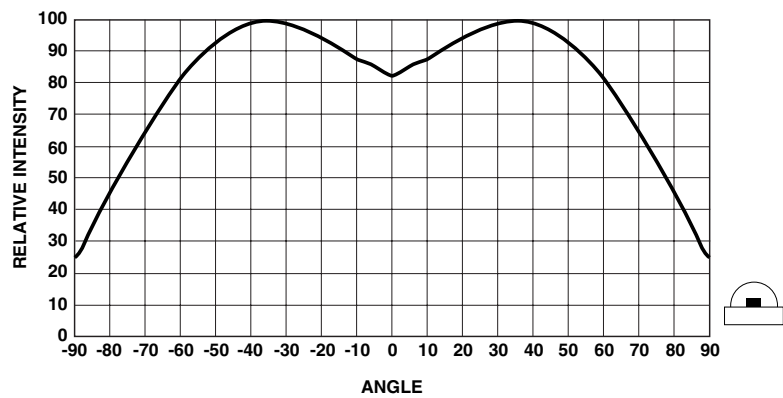


Figure 6. Relative intensity vs. angle for HSMx-C120.



Figure 7. Relative intensity vs. angle for HSMx-C177 and C197.

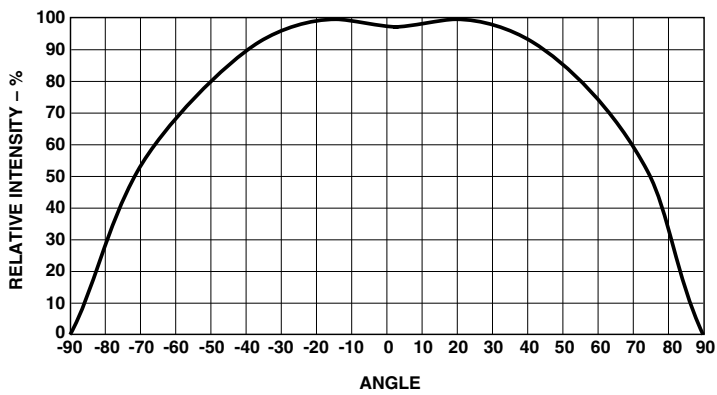


Figure 8. Relative intensity vs. angle for HSMx-C130.

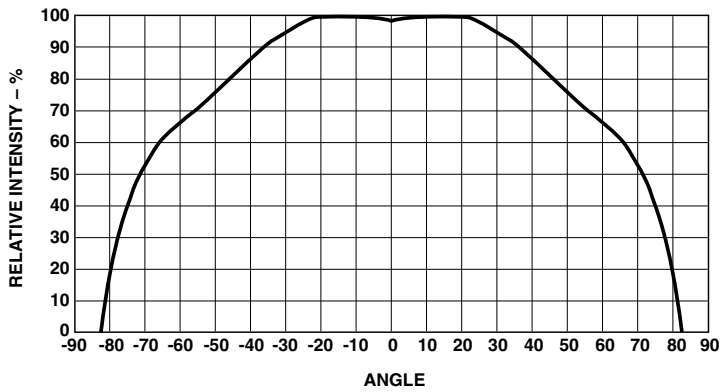


Figure 9. Relative intensity vs. angle for HSMx-C170, C190, C191, and C150.

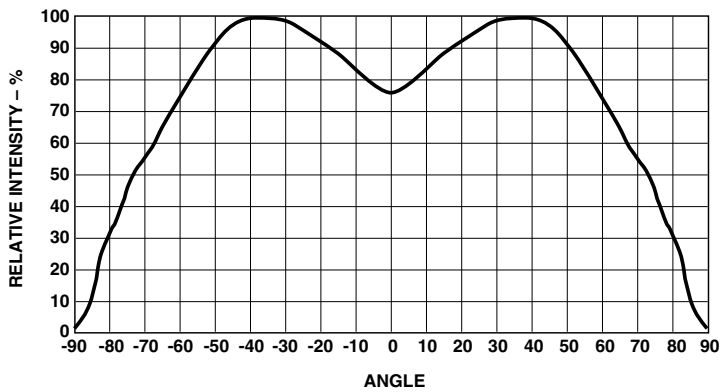


Figure 10. Relative intensity vs. angle for HSMx-C265.

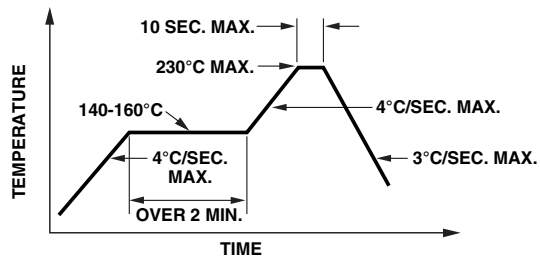


Figure 11. Recommended reflow soldering profile.

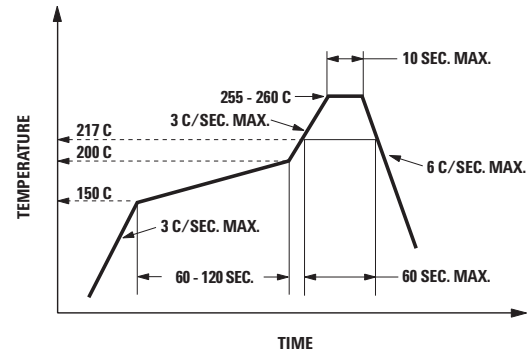


Figure 12. Recommended Pb-free reflow soldering profile.

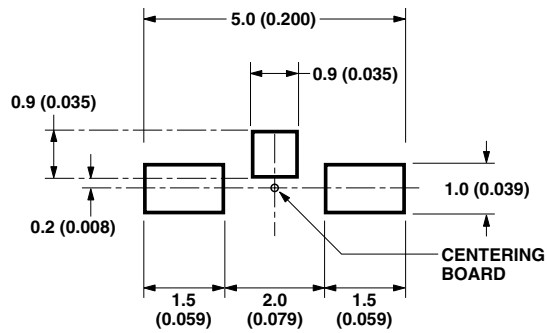


Figure 13. Recommended soldering pattern for HSMx-C110.

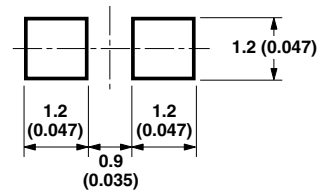


Figure 14. Recommended soldering pattern for HSMx-C170/177.

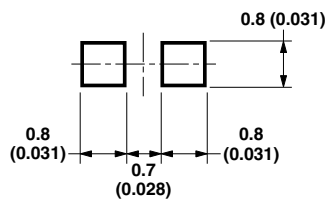


Figure 15. Recommended soldering pattern for HSMx-C130/190/191/197.

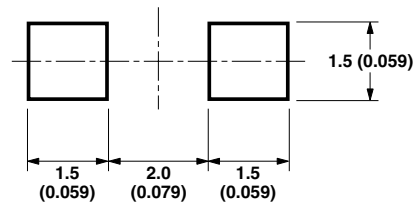


Figure 16. Recommended soldering pattern for HSMx-C150.

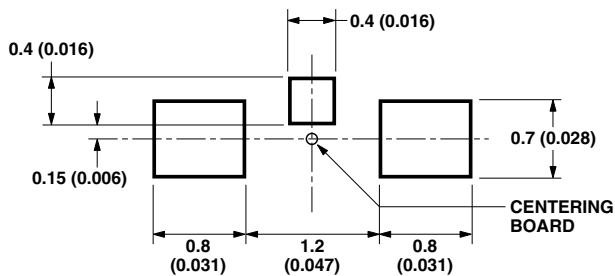


Figure 17. Recommended soldering pattern for HSMx-C120.

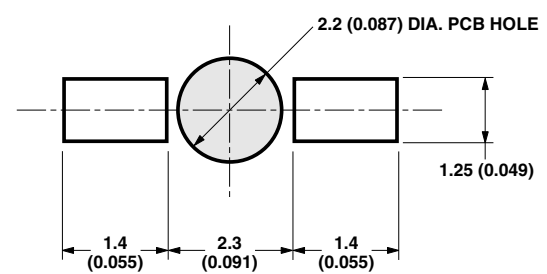


Figure 18. Recommended soldering pattern for HSMx-C265.

NOTE:

1. ALL DIMENSIONS IN MILLIMETERS (INCHES).

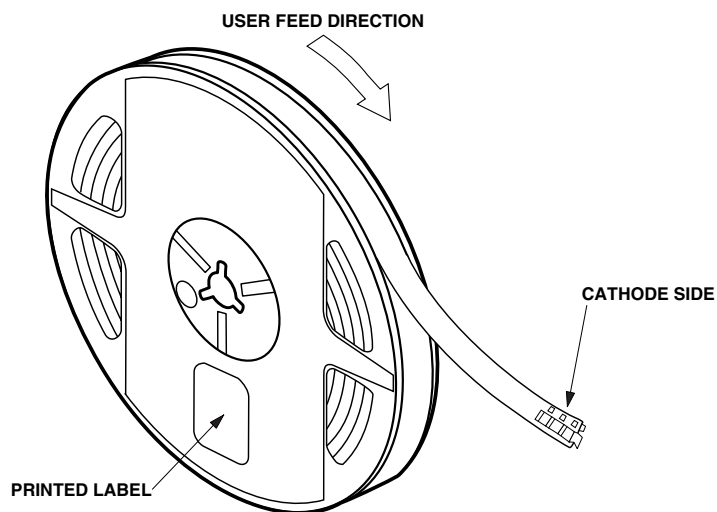


Figure 19. Reeling orientation.

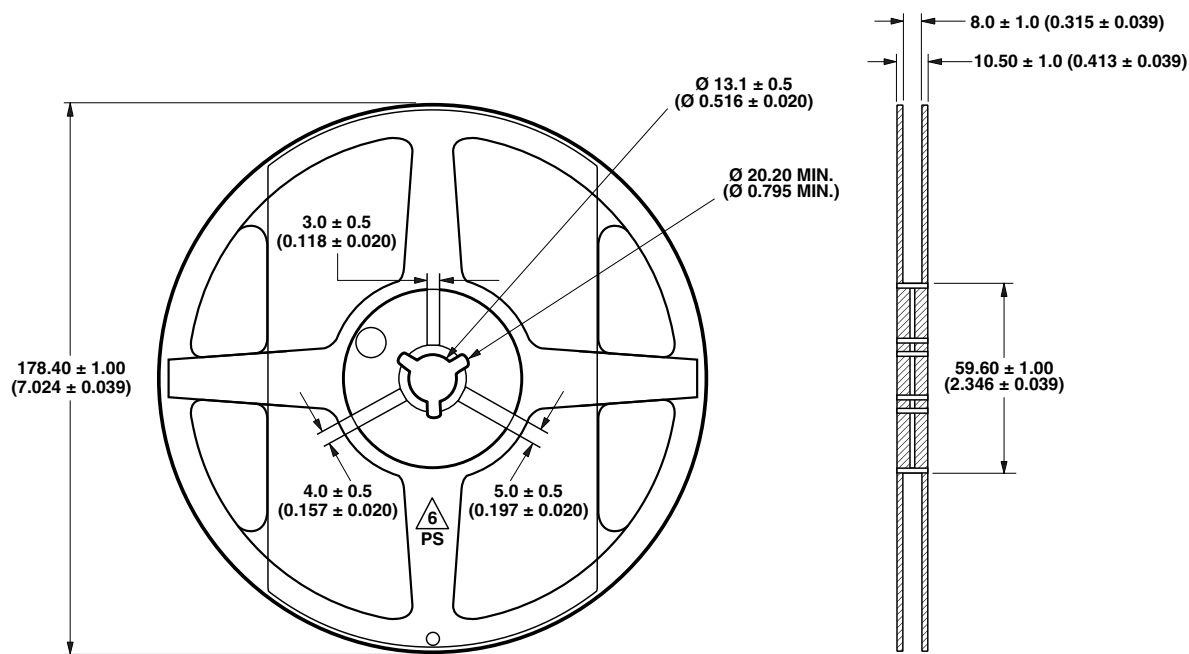


Figure 20. Reel dimensions.

NOTE:

1. ALL DIMENSIONS IN MILLIMETERS (INCHES).

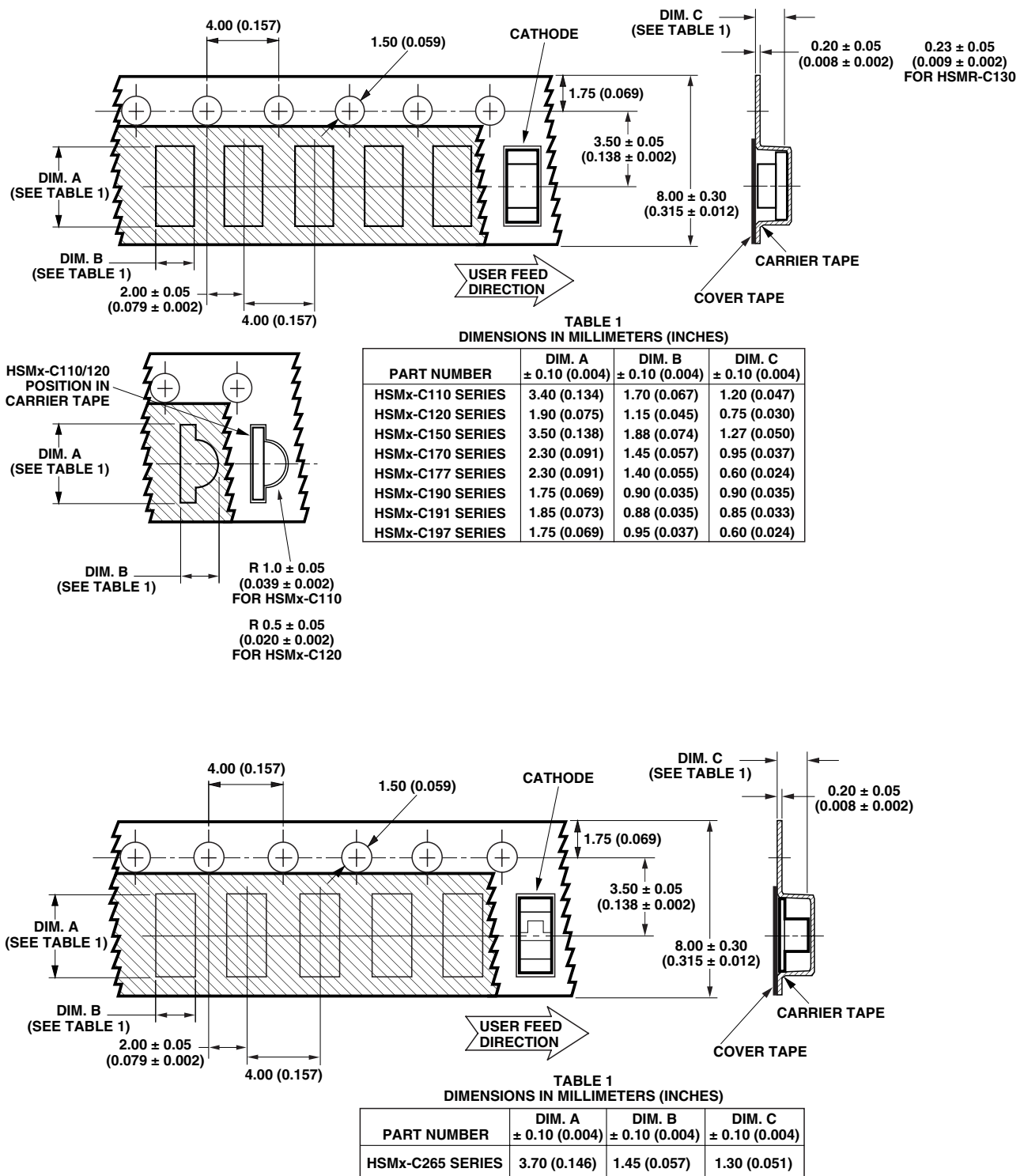


Figure 21. Tape dimensions.

NOTE:
1. ALL DIMENSIONS IN MILLIMETERS (INCHES).

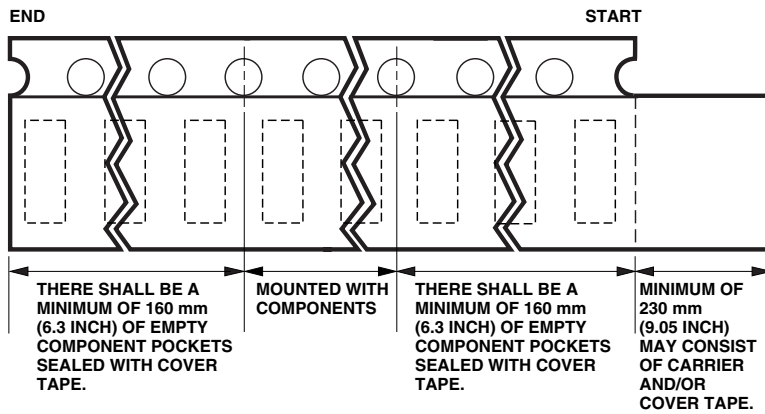


Figure 22. Tape leader and trailer dimensions.

NOTES:

1. ALL DIMENSIONS IN MILLIMETERS (INCHES).
2. TOLERANCE IS ± 0.1 mm (± 0.004 IN.) UNLESS OTHERWISE SPECIFIED.

Convective IR Reflow Soldering

For more information on IR reflow soldering, refer to Application Note 1060, *Surface Mounting SMT LED Indicator Components*.

Storage Condition: 5 to 30°C @ 60% RH max.

Baking is required under the condition:

- a) Humidity Indicator Card is $>10\%$ when read at $23 \pm 5^\circ\text{C}$
- b) Device exposed to factory conditions $<30^\circ\text{C}/60\%$ RH more than 672 hours.

Baking recommended condition: $60 \pm 5^\circ\text{C}$ for 20 hours.

For product information and a complete list of distributors, please go to our website: www.avagotech.com

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